

UNISONIC TECHNOLOGIES CO., LTD

MCR100 SCR

SENSITIVE GATE SILICON CONTROLLED RECTIFIERS REVERSE BLOCKING **THYRISTORS**

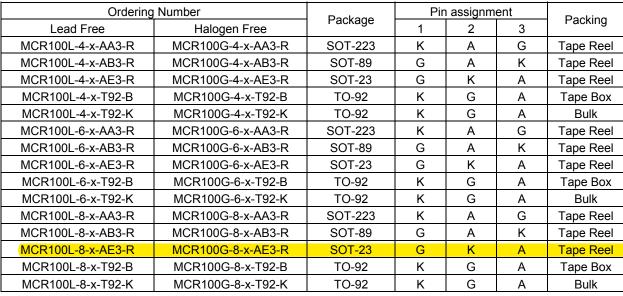
DESCRIPTION

PNPN devices designed for high volume, line-powered consumer applications such as relay and lamp drivers, small motor controls, gate drivers for larger thyristors, and sensing and detection circuits.

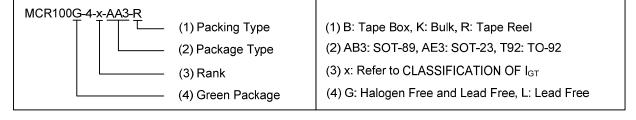
FEATURES

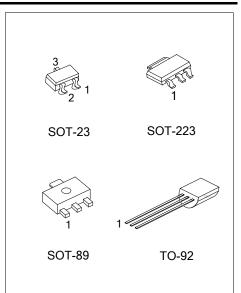
- * Sensitive gate allows triggering by micro controllers and other logic circuits
- * Blocking voltage to 600V
- * On-state current rating of 0.8A RMS at 80°C
- * High surge current capability 10A
- * Minimum and maximum values of I_{GT}, V_{GT} and I_H specified for ease of design
- * Immunity to dV/dt 20V/µsec minimum at 110°C
- * Glass-passivated surface for reliability and uniformity

ORDERING INFORMATION



Note: Pin assignment: G: Gate K: Cathode A: Anode





■ MARKING

| Package | MCR100-4 | MCR100-6 | MCR100-8 | | |
|---------|---|--|---|--|--|
| SOT-223 | MCR100 L: Lead Free G: Halogen Free Date Code L: Lead Free G: Halogen Free -6 Date Code Date Code | | MCR100 L: Lead Free G: Halogen Free Date Code | | |
| SOT-89 | Date Code L: Lead Free G: Halogen Free | Date Code L: Lead Free G: Halogen Free | Date Code L: Lead Free G: Halogen Free | | |
| SOT-23 | R4☐ L: Lead Free G: Halogen Free | R6☐ L: Lead Free G: Halogen Free | R8☐ L: Lead Free G: Halogen Free | | |
| TO-92 | UTC MCR100□ -4 □□□ C: Lead Free G: Halogen Free Date Code | UTC MCR100□ -6 □□□ -6 □□□ Date Code | UTC MCR100□ -8 □□□ -8 □□□ Date Code | | |

■ ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | RATINGS | UNIT | |
|--|---------------------|--------------------|------------------|---|
| Peak Repetitive Off-State Voltage(Note 1) MCR100-4 | | | 200 | V |
| (T _J =-40 ~ 110°C, Sine Wave, 50 ~ 60Hz; | MCR100-6 | V_{DRM}, V_{RRM} | 400 | V |
| Gate Open) | MCR100-8 | | 600 | V |
| On-Sate RMS Current (Tc=80°C) 180°C Cc | I _{T(RMS)} | 0.8 | Α | |
| Peak Non-Repetitive Surge Current (1/2 cycle, Sine Wave, 60Hz, T _J =25°C) | I _{TSM} | 10 | А | |
| Circuit Fusing Considerations (t=8.3 ms) | l ² t | 0.415 | A ² s | |
| Forward Peak Gate Power (T _A =25°C, Pulse | P_GM | 0.1 | W | |
| Forward Average Gate Power (T _A =25°C, t= | $P_{G(AV)}$ | 0.01 | W | |
| Peak Gate Current – Forward (T _A =25°C, Pt | I_{GM} | 1 | Α | |
| Peak Gate Voltage - Reverse (T _A =25°C, Pt | V_{GRM} | 5 | V | |
| Operating Junction Temperature Range (Rated V _{RRM} and V _{DRM}) | T_J | -40 ~ +110 | °C | |
| Storage Temperature Range | T _{STG} | -40 ~ +150 | °C | |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

| PARAMETER | | | SYMBOL | MAX | UNIT |
|---------------------|-------|---------------|---------------|------|------|
| | | SOT-223 | | 180 | °C/W |
| Junction to Ambient | | SOT-23/SOT-89 | θ_{JA} | 400 | °C/W |
| | TO-92 | ı | 200 | °C/W | |

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise stated)

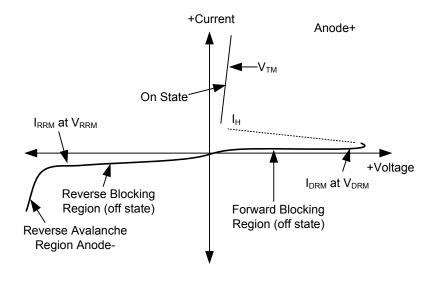
| PARAMETER | | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|-----------------------|--------------------|--|-----|------|-----|------|
| OFF CHARACTERISTICS | | | | | | | |
| Peak Forward or Reverse Blocking | T _C =25°C | | V_D =Rated V_{DRM} and V_{RRM} ; | | | 10 | μA |
| Current | T _C =110°C | IDRM, IRRM | V_D =Rated V_{DRM} and V_{RRM} ; R_{GK} =1k Ω | | | 100 | μΑ |
| ON CHARACTERISTICS | | | | | | | |
| Peak Forward On-State Voltage (No | te 2) | V_{TM} | I _{TM} =1A Peak @ T _A =25°C | | | 1.7 | V |
| Gate Trigger Current (Continuous D | C) (Note3) | I _{GT} | V_{AK} =7Vdc, R_L =100 Ω , T_C =25 $^{\circ}$ C | | 40 | 200 | μΑ |
| Holding Current | T _C =25°C | I _H | V _{AK} =7Vdc, initiating | | 0.5 | 5 | mA |
| Holding Current | T _C =-40°C | | current=20mA | | | 10 | mA |
| Latch Current | T _C =25°C | | V _{AK} =7V, Ig=200μA | | 0.6 | 10 | mA |
| Laten Current | T _C =-40°C | - I _L | | | | 15 | mA |
| Gate Trigger Voltage | T _C =25°C | \/ | V -7Vdo D -4000 | | 0.62 | 0.8 | V |
| (continuous dc) | T _C =-40°C | V_{GT} | V_{AK} =7Vdc, R_L =100 Ω | | | 1.2 | V |
| DYNAMIC CHARACTERISTICS | | | | | | | |
| | · | | V _D =Rated V _{DRM} , Exponential | | | | |
| Critical Rate of Rise of Off-State Voltage | | d _∨ /dt | Waveform, R _{GK} =1000Ω, | 20 | 35 | | V/µs |
| | | | T _J =110°C | | | | |
| Critical Rate of Rise of On-State Current | | di/dt | I _{PK} =20A; Pw=10μsec; | | | 50 | Λ/μς |
| | | ui/ut | diG/dt=1A/µsec, Igt=20mA | | | 30 | A/µs |

Notes: 1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

- 2. Indicates Pulse Test Width≤1.0ms, duty cycle ≤1%.
- 3. Does not include RGK in measurement.

■ VOLTAGE CURRENT CHARACTERISTIC OF SCR

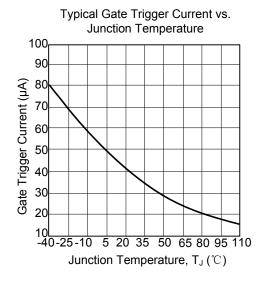
| PARAMETER | SYMBOL |
|---|------------------|
| Peak Repetitive Off Stat Forward Voltage | V_{DRM} |
| Peak Forward Blocking Current | I _{DRM} |
| Peak Repetitive Off State Reverse Voltage | V_{RRM} |
| Peak Reverse Blocking Current | I _{RRM} |
| Peak On State Voltage | V_{TM} |
| Holding Current | I _H |

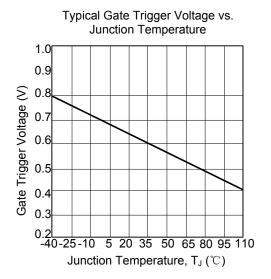


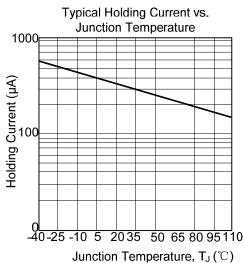
CLASSIFICATION OF I_{GT}

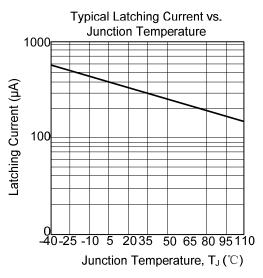
| RANK | В | С | AA | AB | AC | AD |
|-------|----------|----------|--------|---------|---------|---------|
| RANGE | 48~105µA | 95~200µA | 8~16µA | 14~21µA | 19~25µA | 23~52µA |

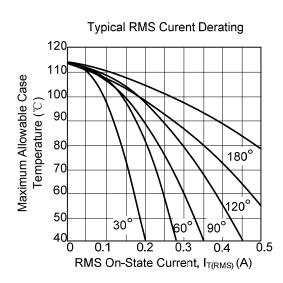
■ TYPICAL CHARACTERISTICS

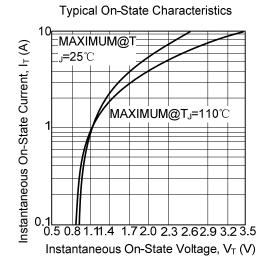












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